<ul> <li>2). In which one of the following circuits both output and input will be in digital format? <ul> <li>a) Analog</li> <li>b) Digital</li> <li>c) Both a and b</li> <li>d) None of the above</li> </ul> </li> <li>3). In which one of the following circuits the input is analog and the output is digital or the input will be digital and the output will be analog? <ul> <li>a) Analog</li> <li>b) Digital</li> <li>c) Mixed</li> <li>d) None of the above</li> </ul> </li> <li>4). Which one of the following is a type of electronic circuit? <ul> <li>a) Analog</li> <li>b) Digital</li> <li>c) Both a and b</li> <li>d) All of the above</li> </ul> </li> <li>5). The diode is a semiconductor device which is made of type of materials</li> </ul>
<ul> <li>input will be digital and the output will be analog? <ul> <li>a) Analog</li> <li>b) Digital</li> <li>c) Mixed</li> <li>d) None of the above</li> </ul> </li> <li>4). Which one of the following is a type of electronic circuit? <ul> <li>a) Analog</li> <li>b) Digital</li> <li>c) Both a and b</li> <li>d) All of the above</li> </ul> </li> <li>5). The diode is a semiconductor device which is made of type of materials</li> </ul>
<ul><li>a) Analog</li><li>b) Digital</li><li>c) Both a and b</li><li>d) All of the above</li><li>5). The diode is a semiconductor device which is made of type of materials</li></ul>
a) One b) Two c) Three d) Four
6). In which material will have an excess of holes? a) P-type b) N-type c) Both a and b d) None of the above
7). In which material will have an excess of electrons? a) P-type b) N-type c) Both a and b d) None of the above
8). In how many ways does the diode can operate? a) One b) Two c) Three d) Four
9). What are the applications of diodes? a) Rectifiers b) Clippers c) Clampers d) All of the above
Which one of the following signals is a continuous and naturally occurring or physically occurring signal?  a) Analog signal b) Digital signal c) Both a and b d) None of the above
The S-R flip flop consist of a) 4 AND gates b) Two additional AND gates c) An additional clock input d) 3 AND gates
What is one disadvantage of an S-R flip-flop?  a) It has no Enable input b) It has a RACE condition c) It has no clock input d) Invalid State  What is the hold condition of a flip-flop?  a) Both S and R inputs activated b) No active S or R input c) Only S is active d) Only R is active
How is a J-K flip-flop made to toggle? a) $J=0, K=0$ b) $J=1, K=0$ c) $J=0, K=1$ d) $J=1, K=1$ In J-K flip-flop, "no change" condition appears when a) $J=1, K=1$ b) $J=1, K=0$ c) $J=0, K=1$ d) $J=0, K=0$

What does the circle on the clock input of a J-K flip-flop mean?
a) Level enabled b) Positive edge triggered c) negative edge triggered d) Level
triggered
What does the direct line on the clock input of a J-K flip-flop mean?
a) Level enabled b) Positive edge triggered c) negative edge triggered d) Level
triggered
Flip flop is at 'set' state when outputs Q and Q' are respectively
a) 1 and 0 b) 0 and 1 c) 1 and 1 d) 0 and 0
D flip flop contains output that are
a) complement b) similar c) infinite d) zero
Flip flop is at 'reset' state when outputs Q and Q' are respectively
a) 1 and 0 b) 0 and 1 c) 1 and 1 d) 0 and 0
Sequential circuits require a
a) timing motors b) timing transformers c) timing generators d) timing
flips
Circuit which has a feedback is
a) combinational circuit b) sequential circuit c) systematic circuit d) correctional circuit
Circuit which has two stable states are termed as
a) combinational circuit b) bistable circuits c) unit stable circuits d) tri stable
circuits
Flip flop is considered set when it stores
a) logic 1 b) logic x c) logic z d) logic 0
If we don't want to change the state of SR flip flop, S and R must be
a) 1 and 0 respectively b) 0 and 1 respectively c) 1 and 1 respectively d) 0 and 0
respectively
Logic circuits which don't have memory are
a) combinational circuit b) sequential circuit c) systematic circuit d) correctional
circuit
Logic circuits that incorporate memory are called
a) combinational circuit b) sequential circuit c) systematic circuit d) correctional
circuit
In order to obtain a P-type germanium, the germanium should be doped with a impurity
A. Trivalent B. Tetravalent C. Pentavalent D. Any of the above
For a germanium P-N junction, the barrier potential is nearly
A.0.15 V B.0.3 V C.0.45 V D.0.6 V/span>
For a silicon P-N junction, the barrier potential is about
A.0.7 V B.0.8 V C.0.9 V D.1.0 V
A zener diode is invariably used with A. Reverse bias B. Forward bias C. Zero bias D. Any of the above
A. Reverse bias B. Forward bias C. Zero bias D. Any of the above The crystal diode is used as a
A.Rectifer B.Amplifier C.Oscillator D.Any of the above

Which of the following is a	passive component?		
A. Vacuum tube devices	B. Capacitors	C. Semiconductor devices	D. All of the
above			
A room temperature P-type	material will have	••	
A.More of electrons B.M.	More of holes C.Equ	ual number of electrons an	d holes
Which of the following elem	ents belog to the sar	ne group of periodic tables	as that of silicon
and germanium			
A.Phosphorous B			
The switching speed is high	in	diode	
Schottky diode PN	diode Both a and	b None of the al	oove
The reverse leakage current	t is	in Schottky did	ode
	c) Ve		
An Analog Signal is continu	ous in both and	l,	
		c) Modulation, waveform	d) Segments,
packets			
Choose the SI unit of electric	_		
(a) Joule (b) Coulo	mb (c) Newton	per coulomb (d) I	Erg
100) Inthe	conductivity lies bet	ween insulator's and cond	uctors?
•	emiconductors		
above			.,
In which one of the followin	g does the electricity	y can't pass?	
	Semiconductors •	_	d) None of the
above			
In which one of the followin	g only a little curren	nt flows?	
a) Insulator's b) S	Semiconductors	c) Conductors	d) None of the
above			
In which one of the followin	g electricity can pas	s easily?	
a) Insulator's b	) Semiconductors	c) Conductors	d) None of the
above			
In which one of the followin	_		
<i>'</i>	Semiconductors	c) Both a and b	d) None of the
above			
What are the advantages of	•		
	neaper c) Stro	ong and not easily destroye	d d) All of the
above		• 0	
The current always enters t			
a) Anode b) Catho	•	and b d) None of the above in 2	ove
The current always exists the	_	<del>-</del>	AOT/O
	•	and b d) None of the ab	oove
14. As the temperature of a			
A.Conductivity increase C.Atomic number decre	· · · · · · · · · · · · · · · · · · ·		06 70 <b>°</b> 0
C.Atomic number decre	tases D. Temp	erature co-efficient become	ES ZEI U

At room temperature N-type	material will have	•••	
A.More of electrons	<b>B.More of holes</b>	C.Equal num	ber of electrons and
holes			
Which of the following eleme	ents belong to the sa	me group of periodic	tables as that of silicon
and germanium			
A.Phosphorous	<b>B.</b> Carbon	C.Sodium D	.Boron
The switching speed is high in	n	diode	
Schottky diode PN d	liode Both a and l	None of t	he above
The switching speed is high in	n	diode	
Schottky diode PN d			he above
Inthe condu			
a) Insulator's b) Se			
above		,	.,
In which one of the following	does the electricity	can't pass?	
a) Insulator's b) So	·	<u>-</u>	d) None of the above
In which one of the following			,
a) Insulator's b) Sei			d) None of the above
In which one of the following		·	,
a) Insulator's b) Se	_	_	d) None of the above
In which one of the following	no current flows?		
a) Insulator's b) Sem	iconductors	c) Both a and b	d) None of the above
What are the advantages of t	he PN junction diod	le?	
a) Smaller b) Chea	per c) Strong an	d not easily destroyed	d) All of the above
The current always enters th	rough	pin?	
a) Anode b) Cathod			e above
The current always exists thr	ough	pin?	
a) Anode b) Cathoo	de c) Both a	and b d) None of the	ne above
14. As the temperature of a s	emiconductor incre	ases its	
A.Conductivity increases	B.Resistivity in	creases	
C.Atomic number decrea	ases D.Tempe	erature co-efficient be	comes zero
At room temperature N-type	material will have	•••	
A.More of electrons	<b>B.</b> More of holes	C.Equal num	ber of electrons and
holes			
Which of the following eleme	ents belog to the sam	ne group of periodic ta	ables as that of silicon
and germanium			
A.Phosphorous	<b>B.</b> Carbon		.Boron
The switching speed is high in			
Schottky diode PN d			he ahove